L Number	Hits	Search Text	DB	Time stamp
1	7	(OLED or "organic light emitting diode" or "organic-light-emitting-diode") with (passivation or dielectric or SiN or "silicon nitride" or "silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or SiO or SiO2 or "silicon oxide" or "silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or "Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or "Si dioxide" or "Si-dioxide" or "silicon O2" or "silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2") with (ion or implant\$ or	USPAT; US-PGPUB	2004/09/16
2	3813535	sputter\$) @ad<20021004	USPAT; US-PGPUB	2004/09/16 13:15
3	3443	OLED or "organic light emitting diode" or "organic-light-emitting-diode"	USPAT: US-PGPUB	2004/09/16
4	40713	(passivation or dielectric or SiN or "silicon nitride" or "silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or "silicon oxide" or "silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or "Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or "Si dioxide" or "Si-dioxide" or "silicon O2" or "silicon-O2" or "silicon-O2" or "silicon-O2" or "silicon-O2" or "silicon-O2" or "silicon-O2" or "silicon-O3" or	USPAT; US-PGPUB	200 1 /09/16 13:16
5	261	(OLED or "organic light emitting diode" or "organic-light-emitting-diode") and ((passivation or dielectric or SiN or "silicon nitride" or "silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or SiO or SiO2 or "silicon oxide" or "silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or "Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or "Si dioxide" or "Si-dioxide" or "silicon O2" or "silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2") with (ion or implant\$ or sputter\$))	USPAT; US-PGPUB	2004/09/16 13:16
7	153	@ad<20021004 and ((OLED or "organic light emitting diode" or "organic-light-emitting-diode") and ((passivation or dielectric or SiN or "silicon nitride" or "silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or "Si.sub.3 N.sub.4" or "silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or "Si oxide" or "silicon O" or "silicon-O" or "Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or "Si dioxide" or "Si-dioxide" or "silicon O2" or "silicon-O2" or "silicon-O3") with (ion or implant\$ or sputter\$)))	USPAT; US-PGPUB	2004/09/16 13:16

8	83079	438/\$7.ccls.	USPAT;	2004/09/16
"		1707 47 .ccis.	US-PGPUB	13:16
9	30	(OLED or "organic light emitting diode" or	USPAT;	2004/09/16
′		"organic-light-emitting-diode") same ((passivation or	US-PGPUB	13:17
		dielectric or SiN or "silicon nitride" or "silicon-nitride" or	as a di ab	15:17
		"Si nitride" or "Si-nitride" or "silicon N" or "silicon-N" or		
		"Si.sub.3N.sub.4" or "Si.sub.3 N.sub.4" or SiO or		
		SiO2 or "silicon oxide" or "silicon-oxide" or "silicon		
		dioxide" or "silicon-dioxide" or "Si oxide" or "Si-oxide"		
		or "silicon O" or "silicon-O" or "Si dioxide" or		
		"Si-dioxide" or "silicon O2" or "silicon—O2" or "silicon		
		O.sub.2" or "silicon-O.sub.2") with (ion or implant\$ or sputter\$))		
10	24	@ad<20021004 and ((OLED or "organic light emitting	USPAT;	2004/09/16
10	21	diode" or "organic-light-emitting-diode") same	US-PGPUB	13:17
		((passivation or dielectric or SiN or "silicon nitride" or	as a a a	17:17
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3		
		N.sub.4" or SiO or SiO2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon ()" or "silicon-()" or		
		"Si dioxide" or "Si-dioxide" or "silicon Q2" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implant\$ or sputter\$)))		
6	6	((OLED or "organic light emitting diode" or	USPAT;	2004/09/16
		"organic-light-emitting-diode") with (passivation or	US-PGPUB	13:17
	}	dielectric or SiN or "silicon nitride" or "silicon-nitride" or	aorarab	1 1 7 1 7
		"Si nitride" or "Si-nitride" or "silicon N" or "silicon-N" or		
		"Si.sub.3N.sub.4" or "Si.sub.3 N.sub.4" or Si() or		
		SiO2 or "silicon oxide" or "silicon-oxide" or "silicon		
		dioxide" or "silicon-dioxide" or "Si oxide" or "Si-oxide"		
	:	or "silicon O" or "silicon-O" or "Si dioxide" or		
		"Si-dioxide" or "silicon O2" or "silicon-O2" or "silicon		
		O.sub.2" or "silicon-O.sub.2") with (ion or implants or		
		sputter\$)) and @ad<20021004		
11	34	(@ad<20021004 and ((OLED or "organic light emitting	USPAT;	2004/09/16
		diode" or "organic-light-emitting-diode") and	US-PGPUB	13:18
ļ		((passivation or dielectric or SiN or "silicon nitride" or	2.2 . 2. 2.2	-
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3N.sub.4" or "Si.sub.3		
		N.sub.4" or Si() or Si()2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon ()" or "silicon-()" or		
		"Si dioxide" or "Si-dioxide" or "silicon 02" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implants or sputters)))) and 438/\$7.ccls.		

12	3	438/\$7.ccls. and (@ad<20021004 and ((OLED or	USPAT;	2004/09/16
		"organic light emitting diode" or	US-PGPUB	13:19
		"organic-light-emitting-diode") same ((passivation or		1
		dielectric or SiN or "silicon nitride" or "silicon-nitride" or		
		"Si nitride" or "Si-nitride" or "silicon N" or "silicon-N" or		
		"Si.sub.3N.sub.4" or "Si.sub.3 N.sub.4" or Si() or		
		SiO2 or "silicon oxide" or "silicon-oxide" or "silicon		
		dioxide" or "silicon-dioxide" or "Si oxide" or "Si-oxide"		
		or "silicon O" or "silicon-O" or "Si dioxide" or		
		"Si-dioxide" or "silicon O2" or "silicon-O2" or "silicon		
		O.sub.2" or "silicon-O.sub.2") with (ion or implant\$ or		
		sputter\$))))		
13	2.1	(@ad<20021004 and ((OLED or "organic light emitting	USPAT;	2004/09/16
'		diode" or "organic-light-emitting-diode") same	US-PGPUB	13:19
		((passivation or dielectric or SiN or "silicon nitride" or	aorarab	',,,,
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3		
		N.sub.4" or Si() or Si()2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or		
		"Si dioxide" or "Si-dioxide" or "silicon O2" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
	,	with (ion or implant\$ or sputter\$)))) not (438/\$7.ccls. and		
		(@ad<20021004 and ((OLED or "organic light emitting		
		diode" or "organic-light-emitting-diode") same		
		((passivation or dielectric or SiN or "silicon nitride" or		
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3		
		N.sub.4" or SiO or SiO2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or		
		"Si dioxide" or "Si-dioxide" or "silicon O2" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implants or sputters)))))		

14	6	(@ad<20021004 and ((OLED or "organic light emitting	USPAT;	2004/09/16
		diode" or "organic-light-emitting-diode") same	US-PGPUB	13:19
		((passivation or dielectric or SiN or "silicon nitride" or	2.0 . 2. 2.2	,
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3N.sub.4" or "Si.sub.3		!
		N.sub.4" or Si() or Si()2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Sí oxide" or "Si-oxíde" or "sílicon ()" or "sílicon-()" or		
		"Si dioxide" or "Si-dioxide" or "silicon ()2" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implant\$)))) not (438/\$7.ccls. and		
		(@ad<20021004 and ((OLED or "organic light emitting		
		diode" or "organic-light-emitting-diode") same		
		((passivation or dielectric or SiN or "silicon nitride" or		
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3N.sub.4" or "Si.sub.3		
		N.sub.4" or Si() or Si()2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon ()" or "silicon-()" or		
		"Si dioxide" or "Si-dioxide" or "silicon O2" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implants))))))		
15	9	@ad<20021004 and ((OLED or "organic light emitting	USPAT;	2004/09/16
		diode" or "organic-light-emitting-diode") same	US-PGPUB	13:19
		((passivation or dielectric or SiN or "silicon nitride" or		
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
ļ		N" or "silicon-N" or "Si.sub.3N.sub.4" or "Si.sub.3		
		N.sub.4" or Si() or Si()2 or "silicon oxide" or		
		"sílicon-oxide" or "sílicon dioxide" or "sílicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or		
		"Si dioxide" or "Si-dioxide" or "silicon O2" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implant\$)))		
16	2553	((438/141) or (438/237) or (438/328) or (438/380)	USPAT;	2004/09/16
		or (438/778) or (438/787) or (438/791) or (438/958)	US-PGPUB	13:21
		or (438/979)).CCLS.		

17	0	(@ad<20021004 and ((OLED or "organic light emitting	USPAT;	2004/09/16
		diode" or "organic-light-emitting-diode") same	US-PGPUB	13:22
		((passivation or dielectric or SiN or "silicon nitride" or		
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3		
		N.sub.4" or SiO or SiO2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon ()" or "silicon-()" or		
		"Si dioxide" or "Si-dioxide" or "silicon 02" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implant\$ or sputter\$)))) and (((438/141) or		
		(438/237) or (438/328) or (438/380) or (438/778) or		
		(438/787) or (438/791) or (438/958) or		
		(438/979)).CCLS.)		
18	0	((@ad<20021004 and ((OLED or "organic light	USPAT;	2004/09/16
		emitting diode" or "organic-light-emitting-diode") same	US-PGPUB	13:22
		((passivation or dielectric or SiN or "silicon nitride" or		
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3N.sub.4" or "Si.sub.3		
		N.sub.4" or SiO or SiO2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon ()" or "silicon-()" or		
		"Si dioxide" or "Si-dioxide" or "silicon 02" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implants or sputters)))) not (438/\$7.ccls. and		
		(@ad<20021004 and ((OLED or "organic light emitting		
		diode" or "organic-light-emitting-diode") same		
		((passivation or dielectric or SiN or "silicon nitride" or		
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3 N.sub.4" or "Si.sub.3		
	i	N.sub.4" or SiO or SiO2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon ()" or "silicon-()" or		
İ		"Si dioxide" or "Si-dioxide" or "silicon 02" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implant\$ or sputter\$)))))) and (((438/141) or		
		(438/237) or (438/328) or (438/380) or (438/778) or		
		(438/787) or (438/791) or (438/958) or		
		(438/979)).CCLS.)		

19	580	((passivation or dielectric or SiN or "silicon nitride" or	USPAT;	2004/09/16
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon	US-PGPUB	13:22
		N" or "silicon-N" or "Si.sub.3N.sub.4" or "Si.sub.3		
		N.sub.4" or Si() or Si()2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon O" or "silicon-O" or		
		"Si dioxide" or "Si-dioxide" or "silicon 02" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
	İ	with (ion or implants or sputters)) and (((438/141) or		
		(438/237) or (438/328) or (438/380) or (438/778) or		
		(438/787) or (438/791) or (438/958) or		
		(438/979)).CCLS.)		
20	528	@ad<20021004 and (((passivation or dielectric or SiN	USPAT;	2004/09/16
		or "sílicon nitride" or "silicon-nitride" or "Sí nitride" or	US-PGPUB	13:22
		"Si-nitride" or "silicon N" or "silicon-N" or		
		"Si.sub.3N.sub.4" or "Si.sub.3 N.sub.4" or Si() or		
		SiO2 or "silicon oxide" or "silicon-oxide" or "silicon		
		dioxide" or "silicon-dioxide" or "Si oxide" or "Si-oxide"		
		or "silicon O" or "silicon-O" or "Si dioxide" or		
		"Si-dioxide" or "silicon O2" or "silicon-O2" or "silicon		
		O.sub.2" or "silicon-O.sub.2") with (ion or implant\$ or		
		sputter\$)) and (((438/141) or (438/237) or (438/328)		
	ļ	or (438/380) or (438/778) or (438/787) or (438/791)		
		or (438/958) or (438/979)).CCLS.))		
21	0	(OLED or "organic light emitting diode" or	USPAT;	2004/09/16
		"organic-light-emitting-diode") and (@ad<20021004 and	US-PGPUB	13:23
		(((passivation or dielectric or SiN or "silicon nitride" or		
		"silicon-nitride" or "Si nitride" or "Si-nitride" or "silicon		
		N" or "silicon-N" or "Si.sub.3N.sub.4" or "Si.sub.3		
		N.sub.4" or SiO or SiO2 or "silicon oxide" or		
		"silicon-oxide" or "silicon dioxide" or "silicon-dioxide" or		
		"Si oxide" or "Si-oxide" or "silicon ()" or "silicon-()" or		
		"Si dioxide" or "Si-dioxide" or "silicon ()2" or		
		"silicon-O2" or "silicon O.sub.2" or "silicon-O.sub.2")		
		with (ion or implant\$ or sputter\$)) and (((438/141) or		
		(438/237) or (438/328) or (438/380) or (438/778) or		
		(438/787) or (438/791) or (438/958) or		
		(438/979)).CCLS.)))		